

Dual N-Channel Enhancement Mode MOSFET

1. Product Information

1.1 Features

- ☒ Surface-mounted package
- ☒ Low thermal resistance

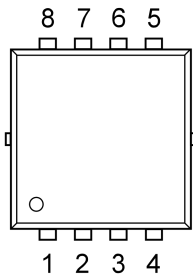
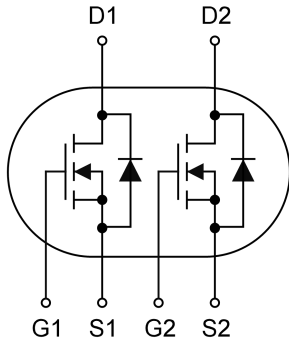
1.2 Applications

- ☒ Motor drivers
- ☒ DC/DC converter

1.3 Quick reference

- ☒ $BV \geq 30\text{ V}$
- ☒ $P_{tot} \leq 20.8\text{ W}$
- ☒ $I_D \leq 34\text{ A}$
- ☒ $R_{DS(ON)} \leq 12\text{ m}\Omega @V_{GS} = 10\text{ V}$
- ☒ $R_{DS(ON)} \leq 17\text{ m}\Omega @V_{GS} = 4.5\text{ V}$

2. Pin Description

Pin	Description	Simplified Outline	Symbol
1	Source(S2)	 Top View PDFN3.3x3.3-8L	
2	Gate(G2)		
3	Source(S1)		
4	Gate(G1)		
5,6	Drain(D1)		
7,8	Drain(D2)		

3. Limiting Values

Symbol	Parameter	Conditions	Min	Max	Unit
V _{DS}	Drain-Source Voltage	T _C =25°C	30	-	V
V _{GS}	Gate-Source Voltage	T _C =25°C	-	±20	V
I _D	Drain Current	T _C =25°C, V _{GS} =10 V	-	34	A
I _{DM} *	Pulsed Source Current	T _C =25°C, V _{GS} =10 V	-	80	A
P _{tot}	Total Power Dissipation	T _C =25°C	-	20.8	W
I _S	Diode Forward Current	T _C =25°C	-	34	A
T _J , T _{stg}	Operating Junction and Storage Temperature Range		-55	150	°C
R _{θJA}	Thermal Resistance-Junction to Ambient		-	62.5	°C/W
R _{θJC}	Thermal Resistance-Junction to Case		-	6	

Notes:

- * Pulse width ≤ 10 μs, duty cycle ≤ 1%.
- ** Surface mounted on 1 in² pad area, t ≤ 10 sec.
- *** Limited by bonding wire.

4. Marking Information

Product Name	Marking
KJ0903QD	0903D XXXXXX

5. Ordering Code

Product Name	Package	Reel size	Tape width	Quantity (pcs)
KJ0903QD	PDFN 3.3x3.3-8L	13"	12 mm	5000

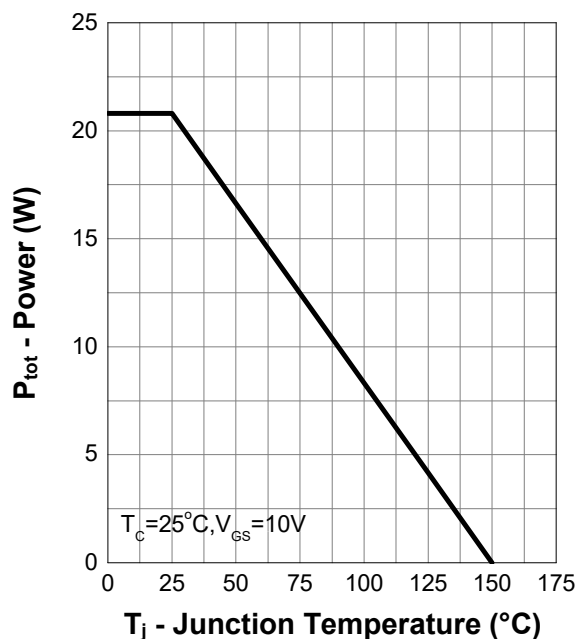
Note: KUIJIEXIN defines "Green" as lead-free (RoHS compliant) and halogen free (Br or Cl does not exceed 900 ppm by weight in homogeneous material and total of Br and Cl does not exceed 1500 ppm by weight; Follow IEC 61249-2-21 and IPC/JEDEC J-STD-020C).

6. Electrical Characteristics (T_A=25°C unless otherwise noted)

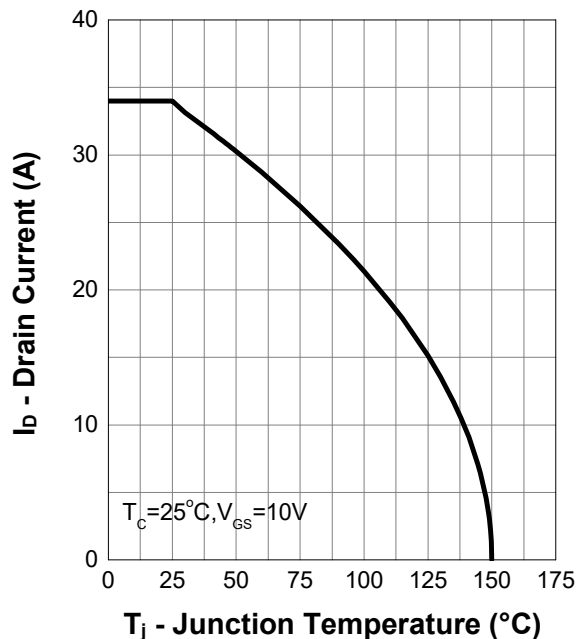
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
Static Characteristics						
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0 V, I _D =250 μA	30	-	-	V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _{DS} =250 μA	0.8	-	1.6	V
I _{DSS}	Zero Gate Voltage Source Current	V _{DS} =24V, V _{GS} =0 V	-	-	1	μA
		T _J =85°C	-	-	30	μA
I _{GSS}	Gate Leakage Current	V _{GS} =±20 V, V _{DS} =0 V	-	-	±100	nA
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =10 V, I _D =20 A	-	10	12	mΩ
		V _{GS} =4.5 V, I _D =10 A	-	15	17	
Diode Characteristics						
V _{SD}	Diode Forward Voltage	I _{SD} =20 A, V _{GS} =0 V	-	-	1.3	V
t _{rr}	Reverse Recovery Time	I _{SD} =20 A, dI _{SD} /dt=100 A/μs	-	16	-	ns
Q _{rr}	Reverse Recovery Charge		-	7	-	nC
Dynamic Characteristics						
C _{iss}	Input Capacitance	V _{GS} =0 V, V _{DS} =15 V, Frequency=1 MHz	-	918	-	pF
C _{oss}	Output Capacitance		-	114	-	
C _{rss}	Reverse Transfer Capacitance		-	101	-	
t _{d(on)}	Turn-on Delay Time	V _{DS} =15 V, V _{GEN} =10 V, R _G =4.5 Ω, R _L =0.75Ω, I _D =20 A	-	7	-	ns
t _r	Turn-on Rise Time		-	55	-	
t _{d(off)}	Turn-off Delay Time		-	19	-	
t _f	Turn-off Fall Time		-	23	-	
Gate Charge Characteristics						
Q _g	Total Gate Charge	V _{GS} =10 V, V _{DS} =15 V, I _{DS} =20 A	-	20	-	nC
Q _{gs}	Gate-Source Charge		-	3.6	-	
Q _{gd}	Gate-Drain Charge		-	3.9	-	

7. Typical Characteristics

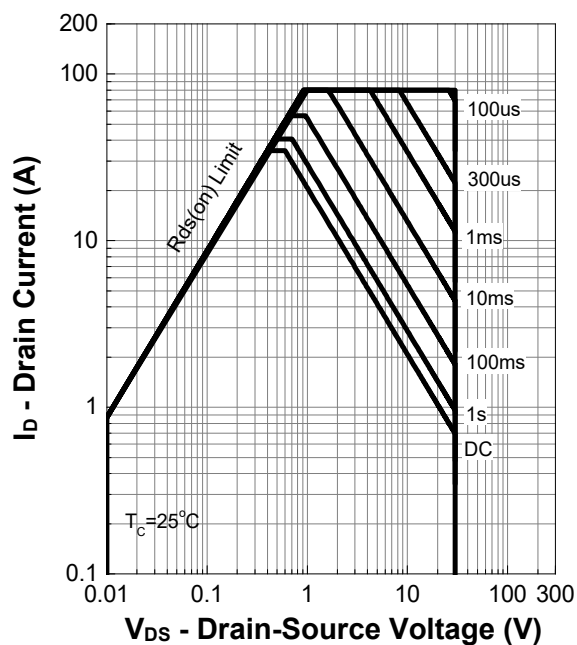
Power Capability



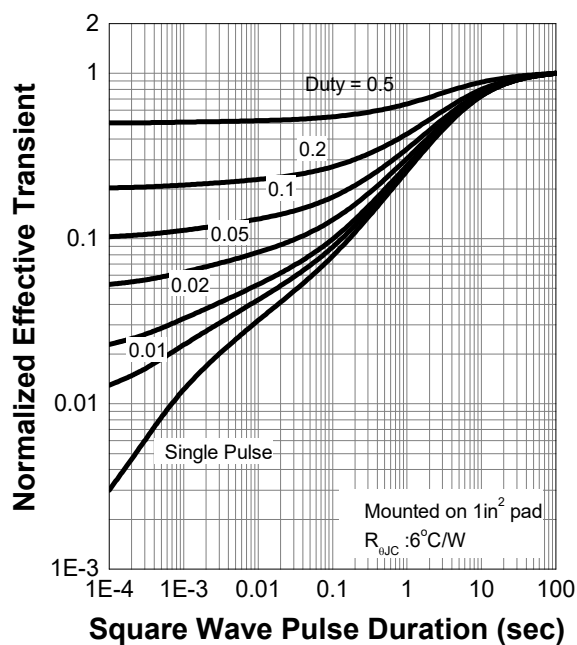
Current Capability



Safe Operation Area

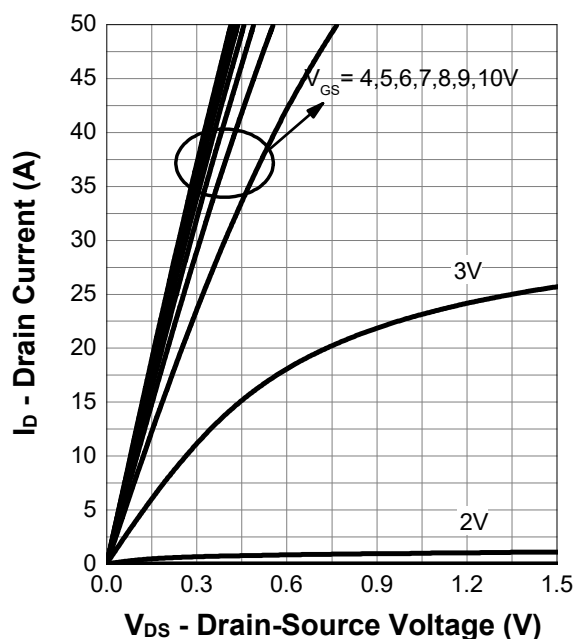


Transient Thermal Impedance

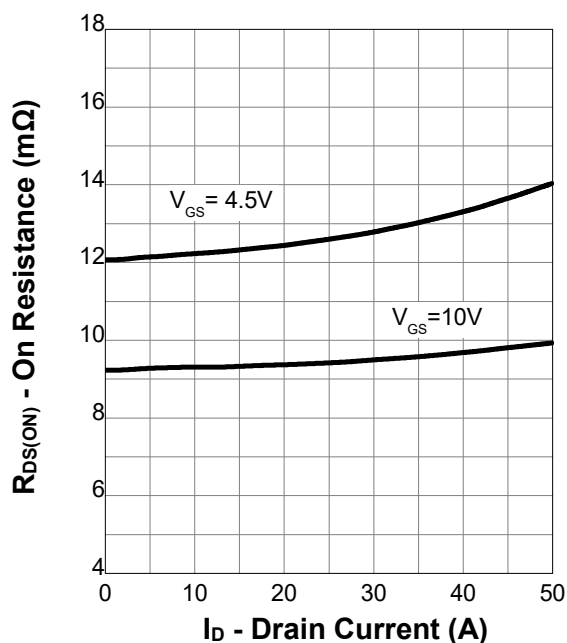


7. Typical Characteristics (cont.)

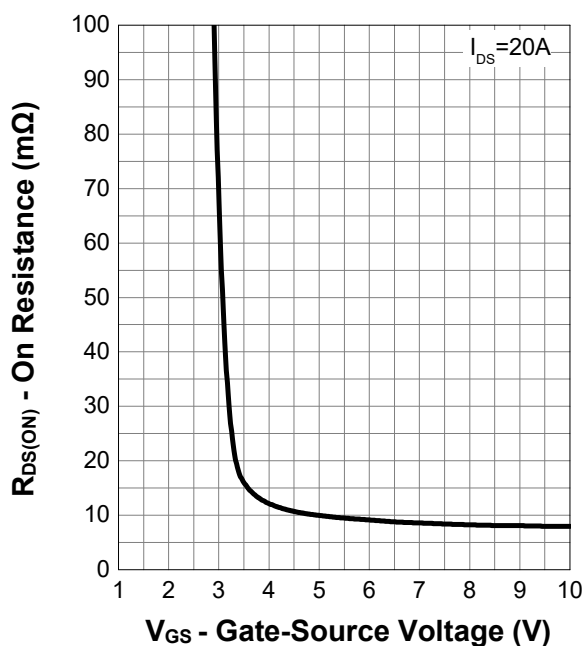
Output Characteristics



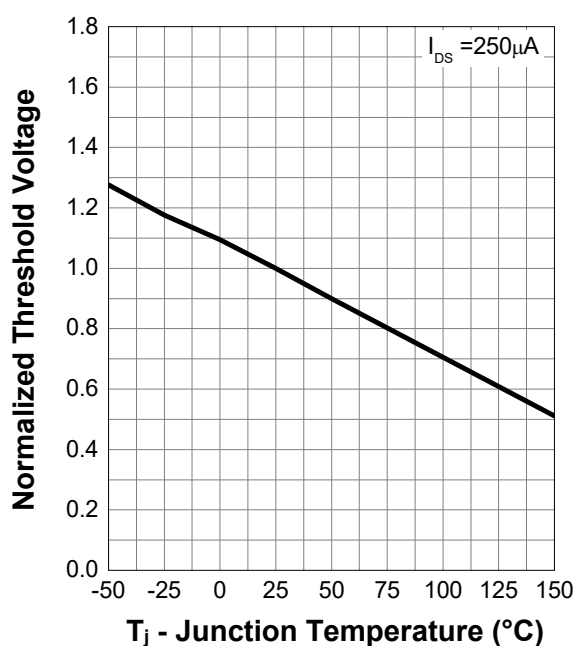
On Resistance



Transfer Characteristics

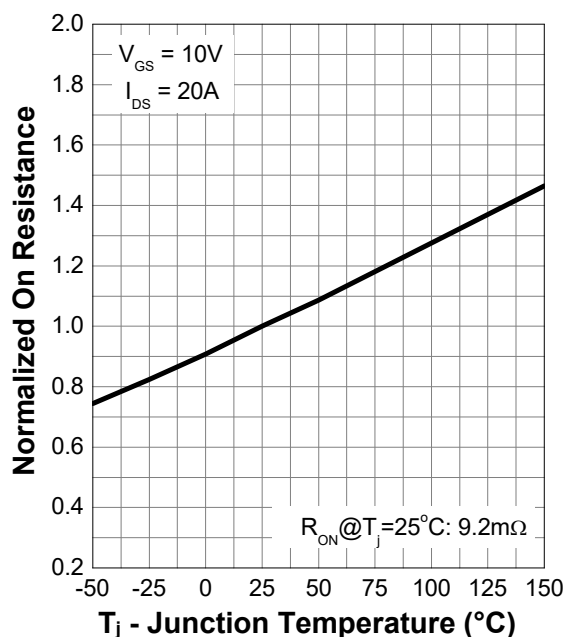


Normalized Threshold Voltage

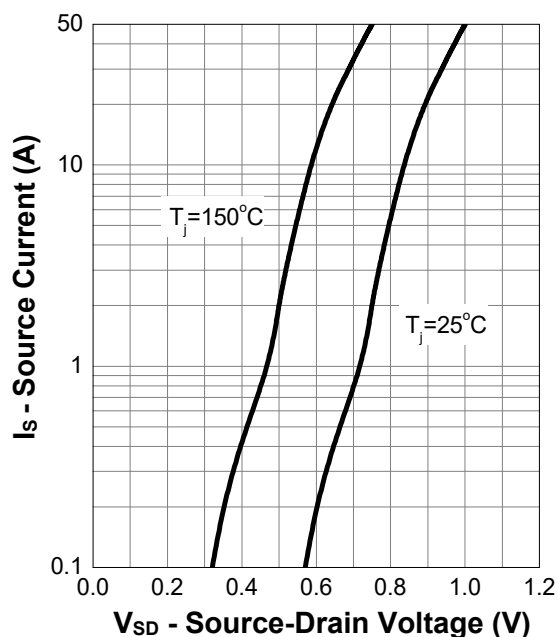


7. Typical Characteristics (cont.)

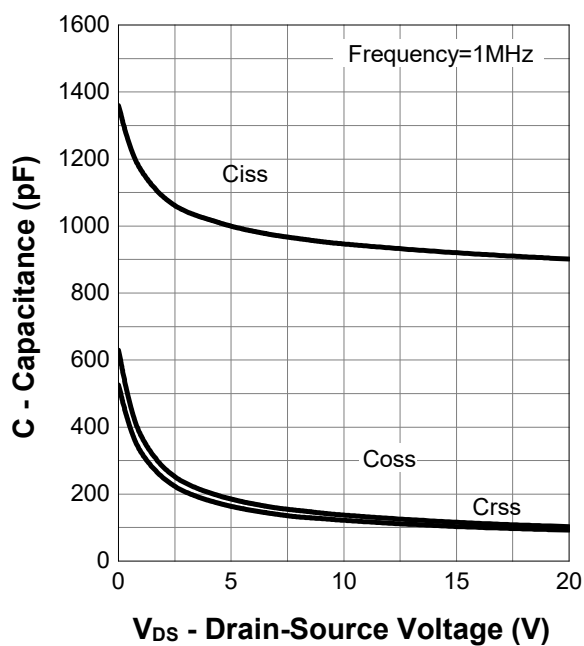
Normalized On Resistance



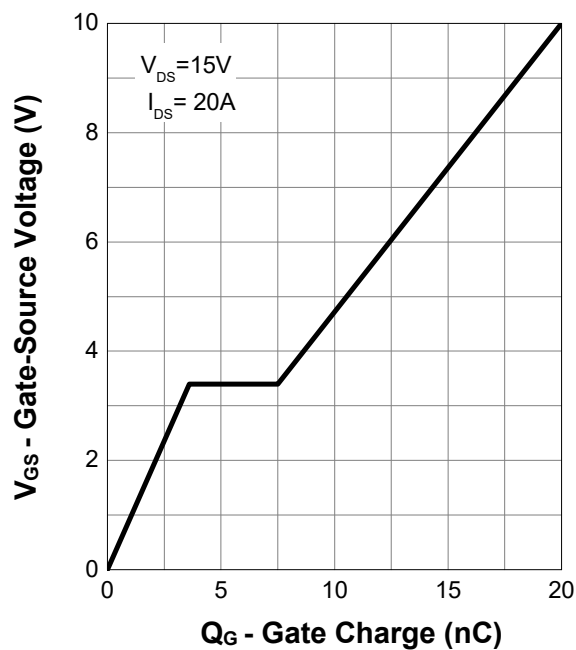
Diode Forward Current



Capacitance

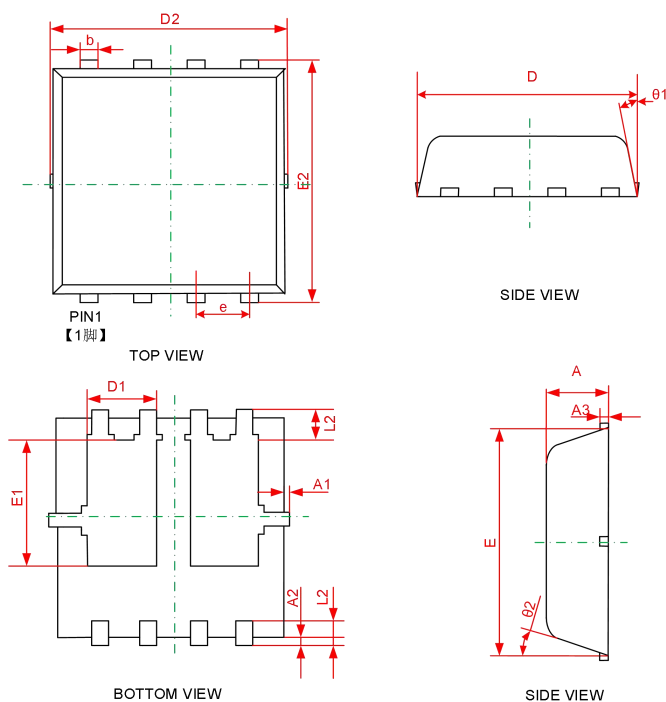


Gate Charge



8. Package Dimensions

PDFN 3.3×3.3-8L Package



Symbol	Dimensions in Millimeters	
	Min	Max
A	0.750	0.850
A1	0.000	0.050
A2	0.100	0.200
A3	0.152 REF.	
b	0.200	0.400
D	3.050	3.250
D1	0.935	1.135
D2	3.200	3.400
E	2.900	3.100
E1	1.635	1.835
E2	3.150	3.350
e	0.625	0.675
L1	0.350	0.450
L2	0.365	0.465
θ1	10°	12°
θ2	10°	12°